

CDMA/FM UPCONVERTER/BPSK MODULATOR

Typical Applications

- CDMA/FM Cellular Systems
- Supports Dual-Mode AMPS/CDMA
- Supports Dual-Mode TACS/CDMA
- Commercial and Consumer Systems
- 3-Cell Battery-Operated Systems

Product Description

The RF9908 is a complete upconverter designed for CDMA/FM cellular applications. The IC contains a double-balanced mixer stage and an output buffer amplifier stage. This device may also be used to directly BPSK modulate a carrier. The mixer is a Gilbert cell with emitter degeneration resistors to provide high IP $_3$. The output stage is a class-B, push-pull configuration to reduce the overall current and still provide a good 50Ω output match. The unit operates at 3.6V and does not require any external matching components other than coupling capacitors. This circuit is designed as part of the RFMD CDMA Chip Set, consisting of a Transmit IF AGC Amp, this Transmit Upconverter, a Receive LNA/Mixer, and a Receive IF AGC Amp.

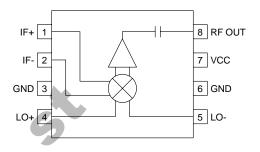
Optimum Technology Matching® Applied

Si BJT

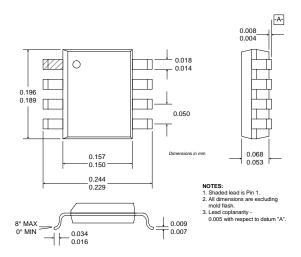
▼ GaAs HBT

☐ GaAs MESFET

☐ Si Bi-CMOS ☐ SiGe HBT ☐ Si CMOS



Functional Block Diagram



Package Style: SOIC-8

Features

- Supports Dual Mode Operation
- +8dBm Input/Output Intercept Point
- Single 3.6V Power Supply
- Internally Matched Inputs and Outputs
- Buffered Output
- Double-Balanced Mixer

Ordering Information

RF9908 CDMA/FM Upconverter/BPSK Modulator RF9908 PCBA Fully Assembled Evaluation Board

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Rev A2 010720

RF9908

Absolute Maximum Ratings

Parameter	Rating	Unit		
Supply Voltage	-0.5 to 7.0	V_{DC}		
Input RF Power	+6	dBm		
Operating Ambient Temperature	-40 to +85	°C		
Storage Temperature	-40 to +150	°C		



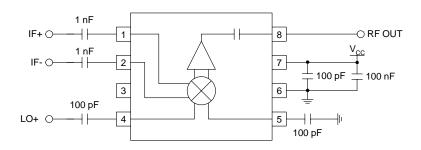
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Parameter	Min.	Тур.	Тур. Мах.		Condition	
Overall					T=25°C, V _{CC} =3.6V, RF=840MHz,	
Overall					LO=970MHz, IF=130MHz	
RF Output Frequency Range		500 to 1500		MHz		
Conversion Gain		0		dB	Over temperature and frequency	
Noise Figure		14		dB		
Output IP3		+8		dBm		
Output ACP		-54		dB	Referenced to a 1.23MHz in-band power. (±885kHz offset)	
Output ALT		-75		dB	Referenced to a 1.23MHz in-band power. (±1.98MHz offset)	
Output VSWR		1.5:1			50Ω	
Spurious Product Rejection		30		dBc	Referenced to RF output	
IF Input						
IF Frequency		DC to 200		MHz		
Differential Input Impedance		265		Ω		
IF to RF Output Isolation		30		dB		
IF to LO Isolation		30		dB		
LO Input						
LO Frequency Range		300 to 1700		MHz		
LO Level		-6 to 0		dBm		
LO to RF Output Leakage		-30	-20	dBm		
RF to LO Isolation		30		dB		
LO Input VSWR		2:1			50Ω	
Power Supply						
Voltage		3.6±5%		V		
Current Consumption		18		mA		

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Pin	Function	Description	Interface Schematic
1	IF+	Balanced IF Input Pin. This pin is internally DC biased and should be DC blocked if connected to a device with a DC level present. For single-ended input operation, one pin is used as an input and the other IF input is AC coupled to ground. The balanced, as well as single-ended, input impedance is 265Ω .	IF+ O IF-
2	IF-	Same as pin 1, except complementary input.	See pin 1.
3	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
4	LO+	Balanced LO Input Pin. This pin is internally DC biased and should be DC blocked if connected to a device with a DC level present. For single-ended input operation, one pin is used as an input and the other LO input is AC coupled to ground. The balanced, as well single-ended, input impedance is 50Ω .	LO+O BIÁS
5	LO-	Same as pin 4, except complementary input.	See pin 4.
6	GND	Same as pin 3.	
7	vcc	Supply Voltage pin. External bypassing is required. External RF, LO, and IF bypassing is required. The trace length between the pin and the bypass capacitors should be minimized. The ground side of the bypass capacitors should connect immediately to ground plane.	
8	RF OUT	RF Output Pin. This pin is internally DC blocked. The output impedance is 50Ω	O RF OUT

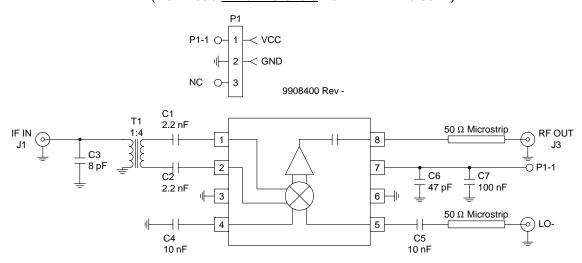
Application Schematic



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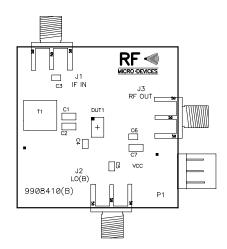
Evaluation Board Schematic

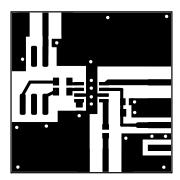
(Download Bill of Materials from www.rfmd.com.)



Evaluation Board Layout Board Size 1.4" x 1.4"

Board Thickness 0.031", Board Material FR-4





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